

6427525 N E C ELECTRONICS INC

05E 22688 D

BIPOLAR ANALOG INTEGRATED CIRCUIT

μPC1213C

T-74-05-01

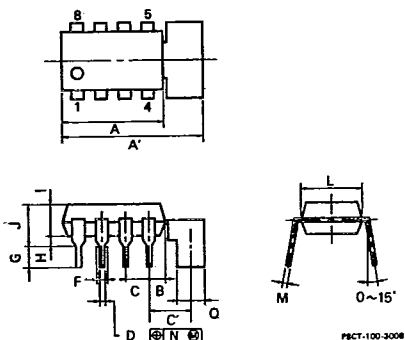
AUDIO POWER AMPLIFIER

DESCRIPTION

The μPC1213C is a silicon monolithic integrated circuit designed for an audio power amplifier used in a portable radio receiver or a portable cassette tape recorder which works at 9-volt power supply.

The μPC1213C is encapsulated in an 8-pin dual in-line plastic package with a tab.

8 PIN PLASTIC DIP WITH TAB (300 mil)



| ITEM | MILLIMETERS | INCHES |
|------|-----------------------|-------------------------|
| A | 12.70 MAX. | 0.500 MAX. |
| A' | 14.50 MAX. | 0.571 MAX. |
| B | 2.54 MAX. | 0.100 MAX. |
| C | 2.54 (T.P.) | 0.100 (T.P.) |
| C' | 3.65 | 0.144 |
| D | 0.50 ^{+0.10} | 0.020 ^{+0.004} |
| F | 1.1 MIN. | 0.043 MIN. |
| G | 3.5 ^{+0.3} | 0.138 ^{+0.012} |
| H | 0.51 MIN. | 0.020 MIN. |
| I | 4.31 MAX. | 0.170 MAX. |
| J | 5.08 MAX. | 0.200 MAX. |
| L | 6.4 | 0.252 |
| M | 0.30 ^{+0.08} | 0.012 ^{+0.003} |
| N | 0.25 | 0.01 |
| Q | 2.62 ^{+0.50} | 0.103 ^{+0.020} |

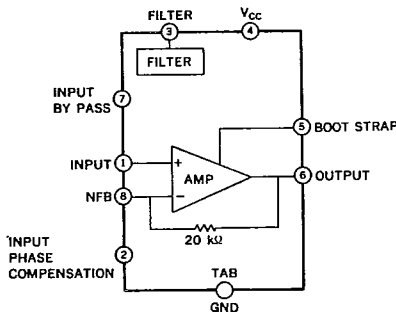
NOTE

1) Each lead centerline is located within 0.25 mm (0.01 inch) of its true position (T.P.) at maximum material condition.

FEATURES

- High output power.
 $P_o = 2.4 \text{ W (TYP.)}$
 at $V_{CC} = 9 \text{ V}$, $R_L = 4 \Omega$, T.H.D. = 10 %
- Wide operating voltage range.
 $V_{CC} = 4.5 \text{ to } 11 \text{ V}$
- High ripple rejection ratio.
 $R.R.R. = 55 \text{ dB (TYP.)}$
- Soft clipping waveform.
- Have a muting circuit so that no shock noise at power supply switch on and off.
- Have a terminal to reject interference noise in strong electric field. (pin 2)

BLOCK DIAGRAM



CONNECTION DIAGRAM

| No. | CONNECTION | No. | CONNECTION |
|-----|------------|-----|------------|
| 1 | INPUT | 5 | BOOTSTRAP |
| 2 | | 6 | OUTPUT |
| 3 | FILTER | 7 | FILTER |
| 4 | VCC | 8 | N. F. B. |
| TAB | GND | | |

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ABSOLUTE MAXIMUM RATINGS (T_a = 25 °C)

| | | | | |
|-----------------------------|------------------|-------------|------------|----|
| Supply Voltage | V _{CC1} | (No Signal) | 16 | V |
| Supply Voltage | V _{CC2} | (Operating) | 11 | V |
| Allowable Power Dissipation | P _d | * | 2.4 | W |
| Operating Temperature | T _{opt} | | -20 to 70 | °C |
| Storage Temperature | T _{stg} | | -40 to 150 | °C |

* 50 x 50 x 0.035 mm³ copper heat sink on P.C.B.

RECOMMENDED CONDITIONS (T_a = 25 °C)

| | |
|----------------|------------------------------------|
| Supply Voltage | V _{CC} = 4.5 to 9 to 11 V |
| Load Impedance | R _L = 4 Ω |

ELECTRICAL CHARACTERISTICS (T_a = 25 °C)

(V_{CC} = 9 V, R = 4Ω, f = 1 kHz, Refer to the test circuit
50 x 50 x 0.035 mm³ copper heat sink on P.C.B. unless otherwise specified)

| CHARACTERISTIC | SYMBOL | MIN. | TYP. | MAX. | UNIT | CONDITION |
|--------------------------------|---------------------|------|------|------|----------------------|--------------------------------------------------|
| Quiescent Circuit Current | I _{CC} | 8 | 15 | 25 | mA | No Signal |
| Open Loop Voltage Gain | A _{vo} | 55 | 65 | | dB | P _O = 0.25 W |
| Voltage Gain (Closed Loop) | A _v | 41 | 45 | 48 | dB | R _f = 100 Ω |
| | | | 34 | | | R _f = 360 Ω |
| Output Power | P _O | 1.8 | 3.6 | | W | T.H.D. = 10% |
| | | | 2.2 | | | R _f = 100 Ω |
| | | | 2.4 | | | V _{CC} = 11 V, R _L = 4 Ω |
| | | | 1.3 | | | V _{CC} = 11 V, R _L = 8 Ω |
| | | | 1.0 | | | V _{CC} = 9 V, R _L = 8 Ω |
| | | | 0.54 | | | V _{CC} = 6 V, R _L = 8 Ω |
| Input Sensitivity | V _{i(rms)} | | 19.5 | | mV | P _O = 2.4 W |
| | | | 47.3 | | | R _L = 4 Ω |
| Input Sensitivity | V _{i(rms)} | | 2.5 | | mV | P _O = 50 mW |
| | | | 8.9 | | | R _L = 4 Ω |
| Total Harmonic Distortion | T.H.D. | | 0.4 | 1.5 | % | P _O = 0.25 W |
| Output Noise Voltage | NL | | 0.2 | 0.8 | mV _{r.m.s.} | R _G = 0 |
| Supply Voltage Rejection Ratio | S.V.R. | 40 | 55 | | dB | R _G = 0, f _{ripple} = 100 Hz |
| Input Impedance | R _i | 10 | 20 | | kΩ | V _{ripple} = 0.3 V _{r.m.s.} |

NOTE: In case that only a TYP. value is specified, this specification is for helping to design.

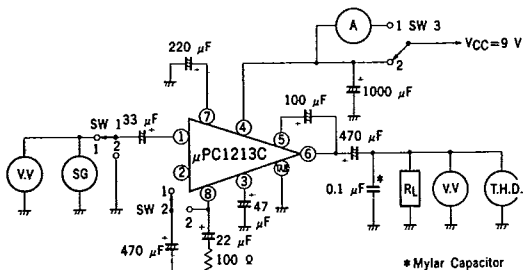
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TEST CIRCUIT
Fig. 1 TEST CIRCUIT

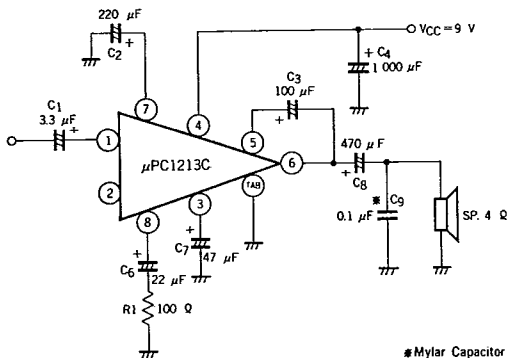
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SWITCH POSITION

| | | SWITCH | | |
|---------------------------|----------|--------|-----|-----|
| | | SW1 | SW2 | SW3 |
| Circuit Current | I_{CC} | 2 | 1 | 1 |
| Open Loop Voltage Gain | A_{VO} | 1 | 2 | 2 |
| Voltage Gain | A_V | 1 | 1 | 2 |
| Output Power | P_O | 1 | 1 | 2 |
| Total Harmonic Distortion | T.H.D. | 1 | 1 | 2 |
| Output Noise Voltage | NL | 2 | 1 | 2 |

TYPICAL APPLICATION
Fig. 2 SINGLE OPERATION



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Fig. 3 BTL OPERATION

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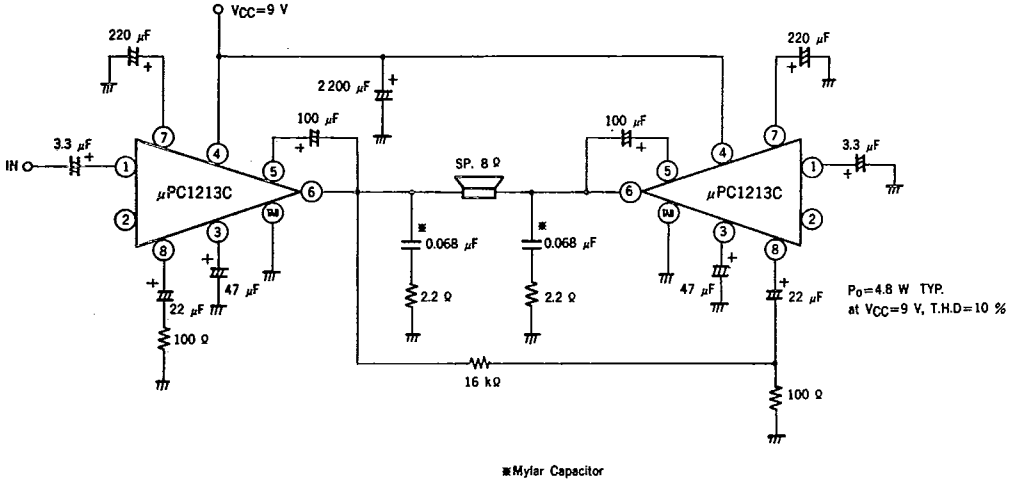
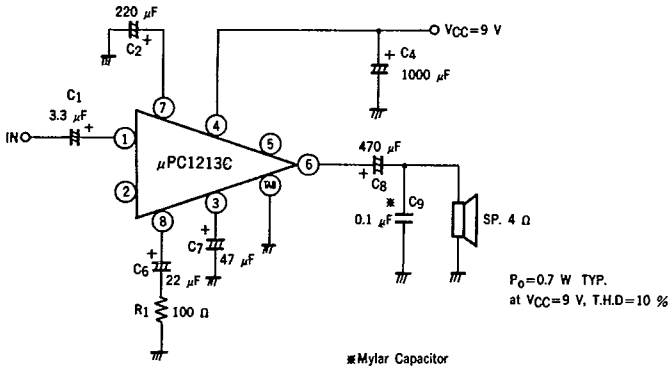


Fig 4 SINGLE OPERATION WITHOUT BOOTSTRAP



NOTE FOR USE

- (1) Capacitor C₉ is for preventing the parastic oscillation.
A mylar capacitor is recommended for this position.
- (2) The ground side of C₄, C₉ and the loud speaker should be attached at the place of the copper foil close to the tab of μPC1212C.
- (3) Interference noise rejection in a strong electric field can be achieved by adding a capacitor (about 1 000 pF) between pin 1 and pin 2.

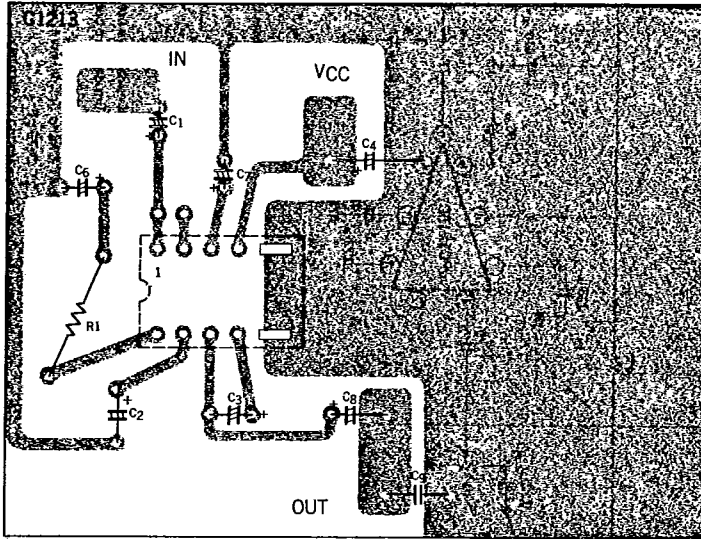
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P.C. BOARD PATTERN (COPPER SIDE)

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TYPICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)

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Fig. 6 OUTPUT POWER vs. SUPPLY VOLTAGE

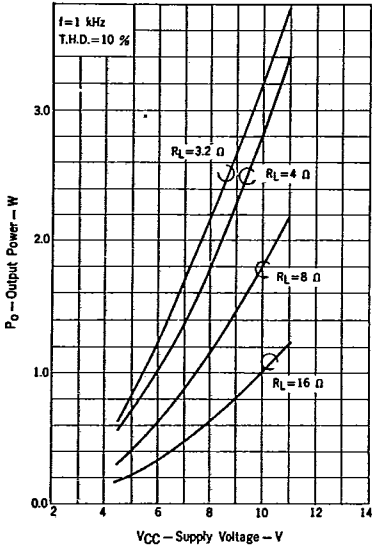


Fig. 7 TOTAL HARMONIC DISTORTION vs. OUTPUT POWER

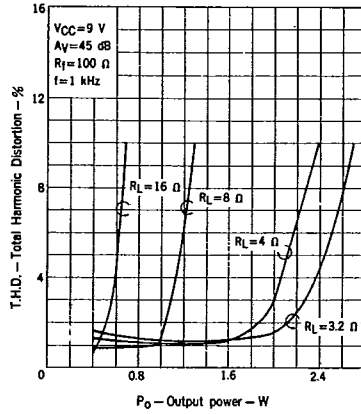
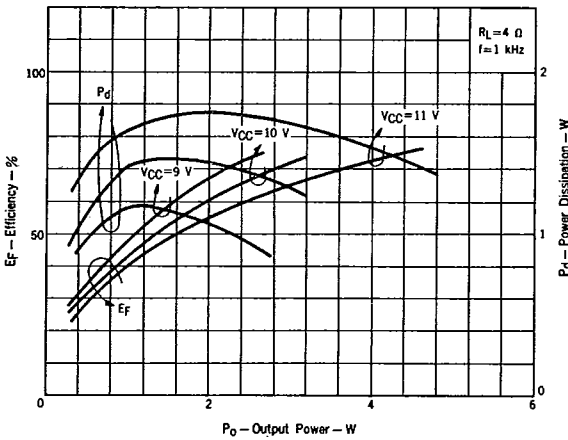


Fig. 8 POWER DISSIPATION AND EFFICIENCY vs. OUTPUT POWER



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Fig. 9 VOLTAGE GAIN (CLOSED LOOP) vs. R_f

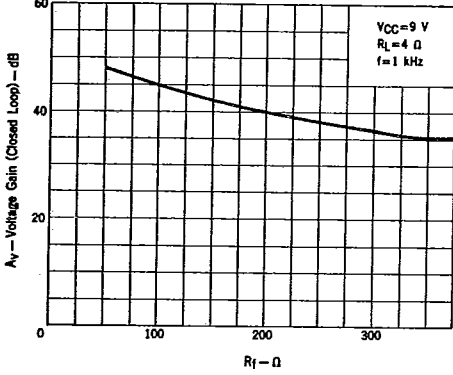


Fig. 10 QUIESCENT OUTPUT VOLTAGE AT PIN 6 vs. SUPPLY VOLTAGE

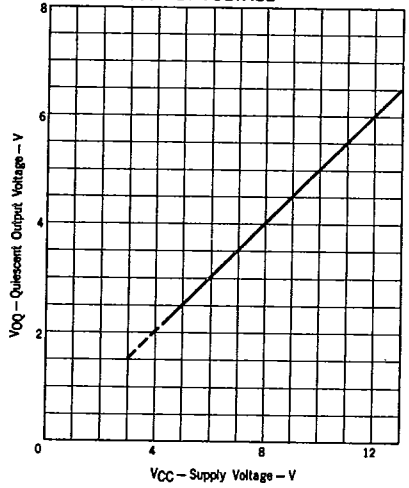


Fig. 11 INPUT SENSITIVITY vs. R_f

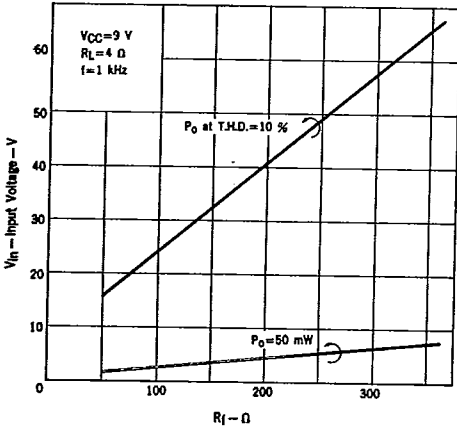
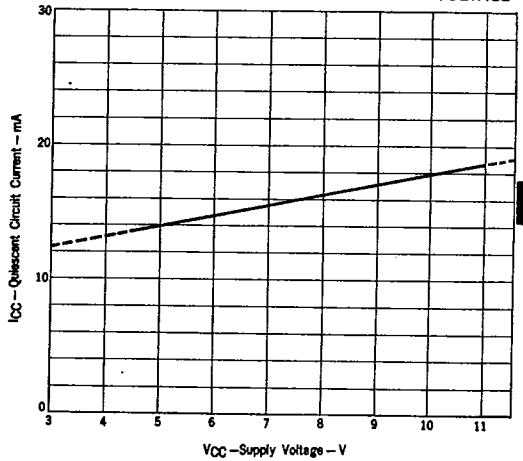


Fig. 12 QUIESCENT CIRCUIT CURRENT vs. SUPPLY VOLTAGE



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Fig. 13 OPEN LOOP VOLTAGE GAIN, VOLTAGE GAIN vs. FREQUENCY

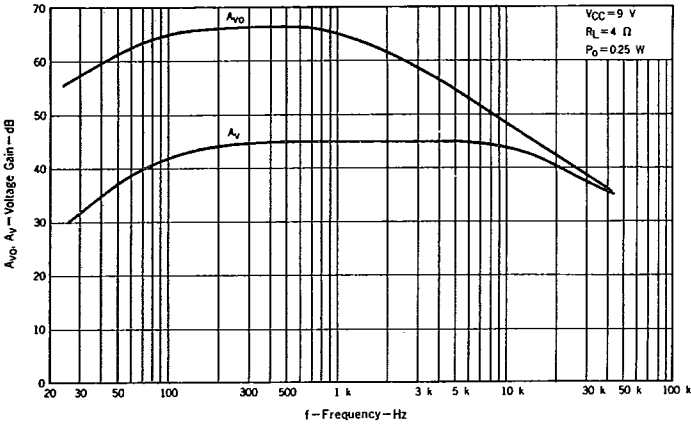


Fig. 14 TOTAL HARMONIC DISTORTION vs. FREQUENCY

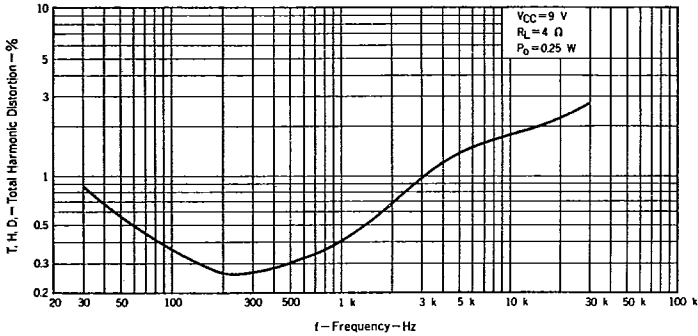
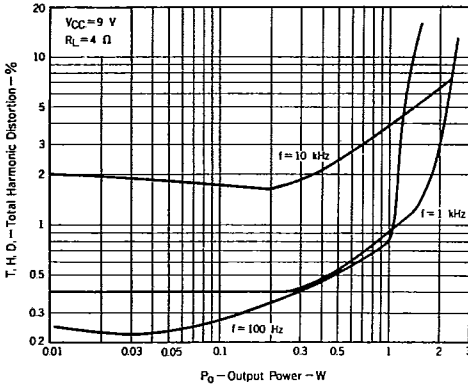


Fig. 15 TOTAL HARMONIC DISTORTION vs. OUTPUT POWER



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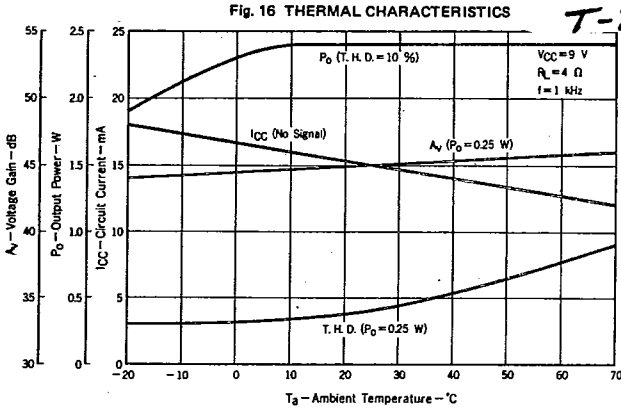


Fig. 17 OPEN LOOP VOLTAGE GAIN, VOLTAGE GAIN vs. SUPPLY VOLTAGE

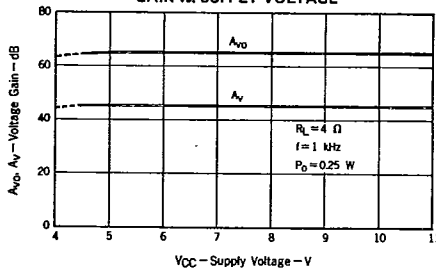
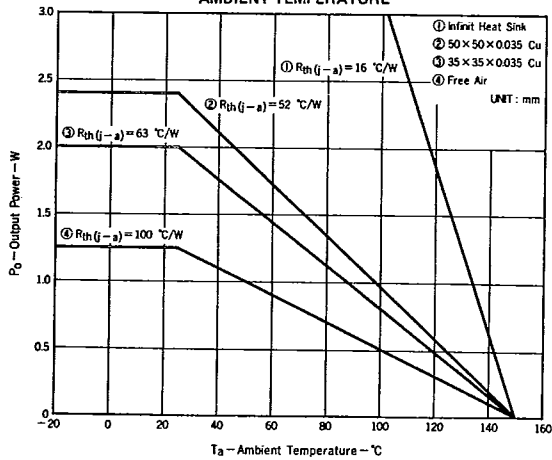


Fig. 18 AVAILABLE POWER DISSIPATION vs. AMBIENT TEMPERATURE



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DESIGN OF HEAT SINK

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Keep much margin at the design of heat sink.

The heat sink shown the following sentence is necessary when the μ PC1213C is operated under next conditions.

| | |
|----------------------------------------|------------|
| Conditions : Maximum Operating Voltage | 10 V |
| Maximum Ambient Temperature | 70 °C |
| Load Impedance | 4 Ω |

There is the equation between junction temperature and thermal resistance.

$$T_j = T_a + R_{th(j-a)} \times P_d \quad (1)$$

T_j : Junction Temperature

T_a : Ambient Temperature

$R_{th(j-a)}$: Thermal Resistance (Junction to Ambient)

P_d : Power Dissipation

According to Fig. 8, $P_d(\text{MAX.}) = 1.42 \text{ W}$ at $V_{CC} = 10 \text{ V}$

And absolute maximum rating shows, $T_j < 150 \text{ }^\circ\text{C}$

From the equation (1) and those values,

$$R_{th(j-a)} < 56.3 \text{ }^\circ\text{C/W} \quad (2)$$

According to Fig. 18, copper size on P.C.B. satisfying the inequality (2) is $50 \times 50 \times 0.035 \text{ mm}^3$.